

## CLP30-200B1

## ASD (Application Specific Devices)

### Overvoltage and overcurrent protection for telecom line

### **Features**

- Dual bidirectional protection device
- High peak pulse current:
  - I<sub>PP</sub> = 40 A (5/310 µs surge)
  - I<sub>PP</sub> = 30 A (10/1000 µs surge)
- Max. voltage at switching-on: 290 V
- Min. current at switching-off: 150 mA



The CLP30-200B1 is designed to protect telecommunication equipment. It provides both a transient overvoltage protection and an overcurrent protection.

The external components (balanced resistors, ring relays contact, ...) needed by the CLP30-200B1 protection concept require very low power rating. This results in a very cost effective protection solution.

## Main applications

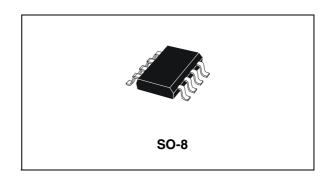
Any telecom equipment submitted to transient overvoltages and lightning strikes such as:

- Analog and ISDN line cards
- PABX

#### **Benefits**

- Voltage and current controlled suppression
- Surface Mounting with SO-8 package
- Very low power rating of external components on line card: balanced resistors, ring relay, low voltage SLIC protection
- TRISILs<sup>TM</sup> are not subject to ageing and provide a fail safe mode in short circuit for a better level of protection. Trisils are used to ensure equipment meets various standards such as UL60950, IEC950 / CSA C22.2, UL1459 and FCC part 68. Trisils have UL94 V0 approved resin (Trisils are UL497B approved [file: E136224]).

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### Order code

Part Number	Marking	
CLP30-200B1RL	CLP30	

Figure 1. CLP30-200B1 schematic diagram

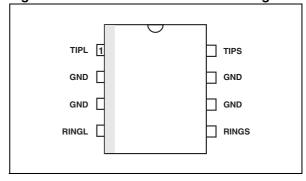
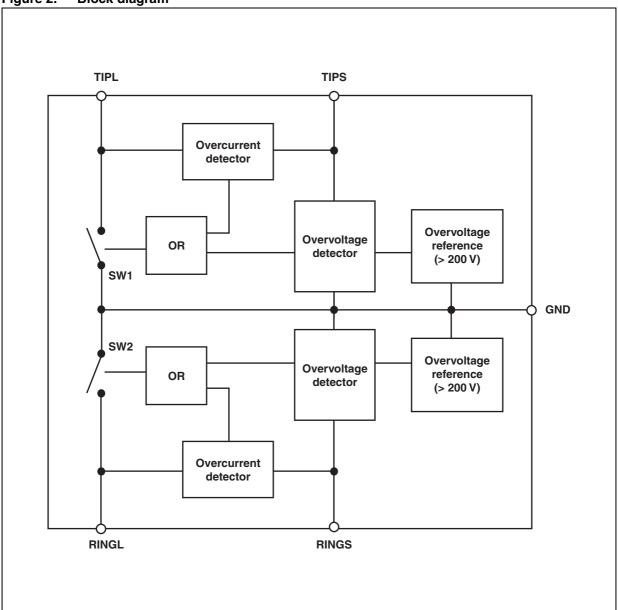


Figure 2. Block diagram



Pin	Symbol	Description
1	TIPL	TIP (line side)
2/3/6/7	GND	Groung
4	RINGL	RING (line side)
5	RINGS	RING ( SLIC side)
8	TIPS	TIP (SLIC side

CLP30-200B1 Characteristics

# 1 Characteristics

Table 1. Standards compliance

Standard	Peak surge voltage (V)	Voltage waveform	Required peak current (A)	Current waveform	Minimum serial resistor to meet standard $(\Omega)$	
GR-1089 Core First level	2500 1000	2/10 μs 10/1000 μs	500 100	2/10 μs 10/1000 μs	12 24	
GR-1089 Core Second level	5000	2/10 μs	500	2/10 μs	24	
GR-1089 Core Intra-building	1500	2/10 μs	100	2/10 μs	0	
ITU-T-K20/K21	6000 1500	10/700 μs	150 37.5	5/310 µs	110 0	
ITU-T-K20 (IEC 61000-4-2)	8000 15000	1/60 ns	ESD contact discharge ESD air discharge		0	
VDE0433	4000 2000	10/700 μs	100 50	5/310 µs	60 10	
VDE0878	4000 2000	1.2/50 µs	100 50	1/20 µs	0	
IEC61000-4-5	4000 4000	10/700 μs 1.2/50 μs	100 100	5/310 μs 8/20 μs	60 0	
FCC Part 68, lightning surge type A	1500 800	10/160 μs 10/560 μs	200 100	10/160 μs 10/560 μs	22.5 15	
FCC Part 68, lightning surge type B	1000	9/720 µs	25	5/320 µs	0	

Table 2. Thermal resistance

Symbol	Paramete	Value	Unit
R <sub>th(j-a)</sub>	Junction to ambient	170	° C/W

Characteristics CLP30-200B1

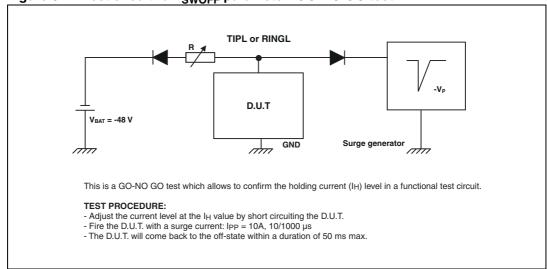
Table 3. Absolute maximum ratings ( $R_{SENSE} = 3 \Omega$ ,  $T_{amb} = 25^{\circ} C$ )

Symbol	Parameter			Unit
I <sub>PP</sub>	Line to GND peak pulse current  – 10/1000 μs (open circuit voltage wave shape 10/1000 μs)  – 5/310 μs (open circuit voltage wave shape 10/700 μs)		30 40	А
I <sub>TSM</sub>	Non repetitive surge peak on-state current F = 50 Hz	$t_p = 10 \text{ ms}$ $t_p = 200 \text{ ms}$ $t_p = 1 \text{ s}$	8.5 4.5 3.5	А
T <sub>stg</sub> T <sub>j</sub>	Storage temperature range Maximum junction temperature		-40 to +150 150	°C
T <sub>L</sub>	Lead temperature for soldering during 10 s.		260	°C

Table 4. Electrical characteristics ( $R_{SENSE} = 3 \Omega$ ,  $T_{amb} = 25^{\circ} C$ )

Symbol	Parameter Test condtions		Min	Max	Unit
I <sub>LGL</sub>	Line to GND leakage current	V <sub>LG</sub> = 200 V Measured between TIP (or RING) and GND		10	μΑ
$V_{LG}$	Line to GND operating voltage			200	V
V <sub>SWON</sub>	Line to GND voltage at SW1 or SW2 switching-on	Measured at 50 Hz between TIPL (or RINGL) and GND,one cycle		290	V
I <sub>SWOFF</sub>	Line to GND negative current at SW1 or SW2 switching-off	Refer to test circuit fig 9	150		mA
I <sub>SWON</sub>	Line current at SW1 or SW2 switching-on	Positive surge Negative surge	220 280	320 380	mA
С	Line to GND capacitance	$V_{LG} = 0 V$ $V_{OSC} = 200 \text{ mV}_{RMS} \text{ F} = 1 \text{MHz}$		100	pF

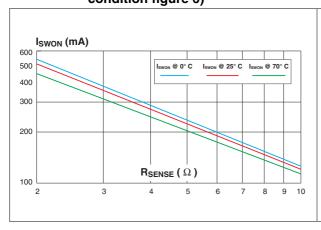
Figure 3. Test circuit for I<sub>SWOFF</sub> parameter: GO-NO GO test



CLP30-200B1 Characteristics

Figure 4. Typical variation of switching-on current (positive or negative) versus R<sub>SENSE</sub> resistor and junction temperature (see test condition figure 6)

Figure 5. Variation of switching-on current versus R<sub>SENSE</sub> at 25° C



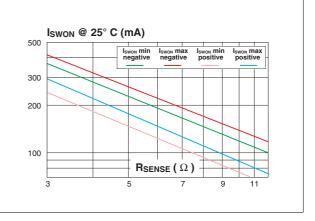
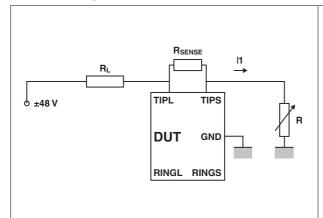
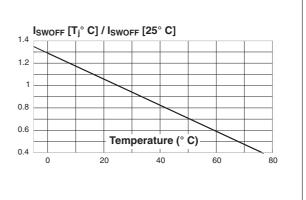


Figure 6. I<sub>SWON</sub> MEASUREMENT:

- I<sub>SWON</sub> = I1 when the CLP30-200B1 switches on (I1 is progressively increased using R)
- Both TIP and RING sides of the CLP30-200B1 are checked
- $-RL = 10 \Omega$

Figure 7. Relative variation of switching-off current versus junction temperature (for R<sub>SENSE</sub> between 3 and 10  $\Omega$ )

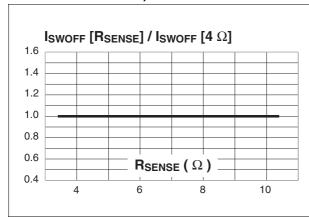




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Figure 8. Relative variation of switching-off current versus  $R_{SENSE}$  (between 3 and 10  $\Omega$ )

Figure 9. Relative variation of switching-on voltage versus dV/dt with an external resistor of 3  $\Omega$ 



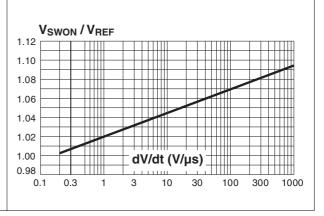
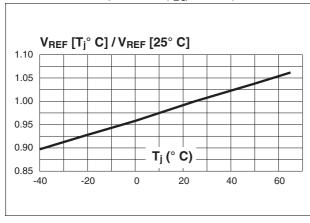


Figure 10. Relative variation of internal reference voltage versus junction temperature (I<sub>LG</sub> =1 mA)

Figure 11. Capacitance (TIP/GND) versus applied voltage (typical values)



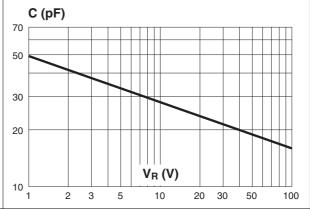
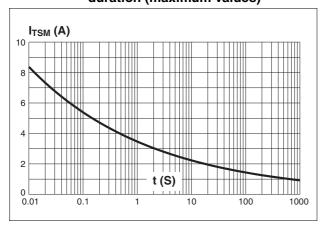


Figure 12. Surge peak current versus overload duration (maximum values)



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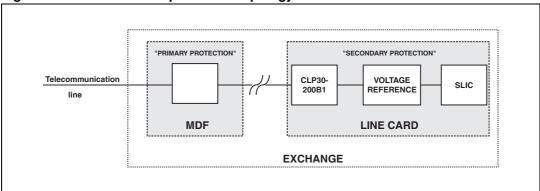
CLP30-200B1 Technical information

### 2 Technical information

#### 2.1 Introduction

The aim of this section is to show the behavior of our new telecom line protection device.

Figure 13. Suscriber line protection topology



*Figure 13.* is a simplified block diagram of a subscriber line protection that is mainly used so far. This shows two different things:

- A "primary protection" located on the Main Distribution Frame (MDF) eliminates coarsely the high energy environmental disturbances (lightning transients and AC power mains disturbances) for which the ITU-T-K20 requires a 4 kV 10/700 µs test. This can be assumed either by gas-tubes or silicon protection such as the TLPxxM.
- A "secondary protection" located on the line card eliminates finely the remaining transients that have not been totally suppressed by the first stage. The ITU-T-K20 requires a 1 kV 10/700 µs test. At this stage, the protection is managed by the CLP30-200B1.

The explanations which follow are basically covering the line card application.

## 2.2 STMicroelectronics CLP30-200B1 concept

### 2.2.1 Evolution of the SLIC protection

Over the years, the performances of the SLICs considerably increased and therefore the need of the protection has also evolved.

The CLP30-200B1 is especially designed for the protection of this new generation of SLIC. For this, it is based on both overvoltage and overcurrent protection modes.

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**Technical information** CLP30-200B1

Figure 14. Line card protection

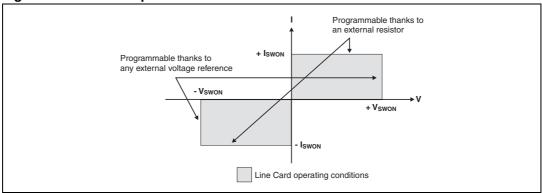
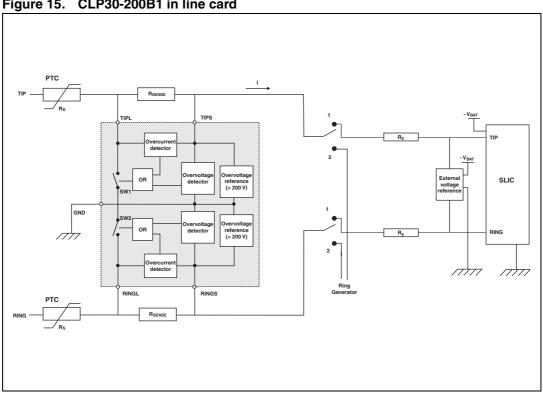


Figure 14. summarises the performance of the CLP30-200B1 which basically holds the SLIC inside its correct voltage and current values.

#### 2.2.2 **Application circuit**

Figure 15. CLP30-200B1 in line card



The Figure 15. above shows the topology of a protected analog subscriber line at the line card side.

■ A first stage based on CLP30-200B1 manages the high power issued from the external surges. When used in ringing mode, the CLP30-200B1 operates in voltage mode and provides a symmetrical and bidirectional overvoltage protection above 200 V on both TIP and RING lines. When used in speech mode, the CLP30-200B1 operates in current mode and the activation current of the CLP30-200B1 is adjusted by R<sub>SENSE</sub>.

CLP30-200B1 **Technical information** 

> ■ A second stage which is the external voltage reference device defines the firing threshold voltage during the speech mode and also assumes a residual power overvoltage suppression. This stage can be either a fixed or programmable device such as LCP1511D.

#### 2.2.3 Ringing mode

1/2 CLP200M

Figure 16. Switching by voltage during ringing mode

In ringing mode (ring relay in position 2), the only protection device involved is the CLP30-200B1.

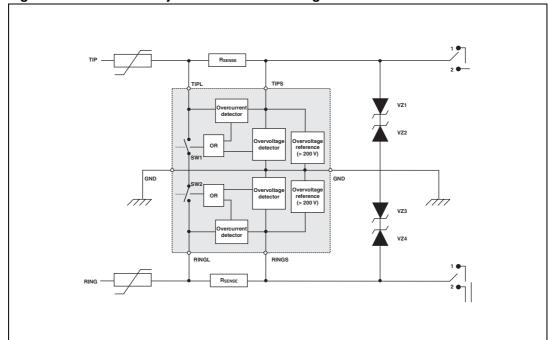
In normal conditions, the CLP30-200B1 operates in region 1 of A1 curve, and is idle.

If an overvoltage occurring between TIP (or RING) and GND reaches the internal overvoltage reference (+/- 200 V), the CLP30-200B1 acts and the line is short-circuited to GND. At this time the operating point moves to region 2 for positive surges (region 3 for negative surges). Once the surge current disappears, the device returns to its initial state (region 1).

For surges occurring between TIP and RING, the CLP30-200B1 acts in the same way. This means that the CLP30-200B1 ensures a tripolar protection.

When used alone, the CLP30-200B1 acts at the internal overvoltage reference level (+/- 200V). Furthermore, it is possible to adjust this threshold level to a lower voltage by using up to 4 fixed external voltage reference ( $V_{Z1}$  to  $V_{Z4}$ ) (see *Figure 17*.).

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Method to adjust the reference voltage

#### 2.2.4 Speech mode

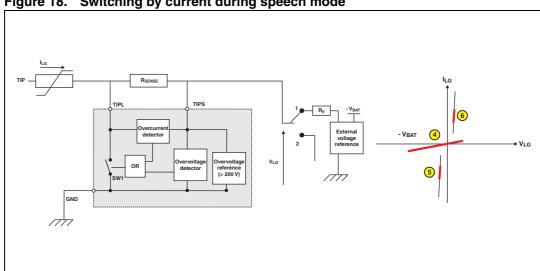


Figure 18. Switching by current during speech mode

In speech mode (ring relay in position 1), the protection is provided by the combination of both CLP30-200B1 and the external voltage reference device (for example LCP1511D).

In normal conditions, the working point of this circuit is located in region 4 of A2 curve: the CLP30-200B1 is idle.

When a surge occurs on the line, the external voltage reference device clamps at GND or -V<sub>BAT</sub> respectively for positive and negative surges. This generates a current which is detected by R<sub>SENSE</sub> and causes the protection to act: the line is short-circuited to GND. The operating point moves to region 6 for positive surges or region 5 for negative surges.

CLP30-200B1 Technical information

Once the surge current falls below the switching-off current  $I_{SWOFF}$  the CLP30-200B1 returns to its initial state (**region 4**).

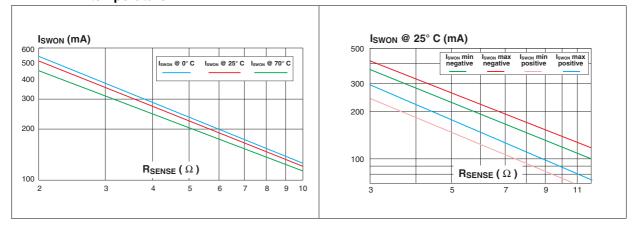
Furthermore, the CLP30-200B1 switches when an overvoltage, either positive or negative, occurs either:

- simultaneously on both TIP and RING lines versus GND
- between TIP and RING
- on TIP (or RING) versus GND

The choice of the switching-on current is function of the R<sub>SENSE</sub> resistors.

Figure 19. Switching-on current versus
R<sub>SENSE</sub>: relative variation of I<sub>SWON</sub>
versus R<sub>SENSE</sub> at various
temperature

Figure 20. Switching-on current versus  $R_{SENSE}$ : relative variation of  $I_{SWON}$  versus  $R_{SENSE}$  at  $T_{amb}$  = 25° C



This current (typically above 150 mA) should not activate the protection device CLP30-200B1.

Therefore the level of activation is to be chosen just below this limit (typically 200 mA). This level is adjusted through  $R_{SENSE}$ .

Figures 7a and 7b enable the designers to choose the right R<sub>SENSE</sub> value.

#### Example

The choice of  $R_{SENSE}$  = 3  $\Omega$  ensures a negative triggering of -280 mA min and -380 mA maximum.

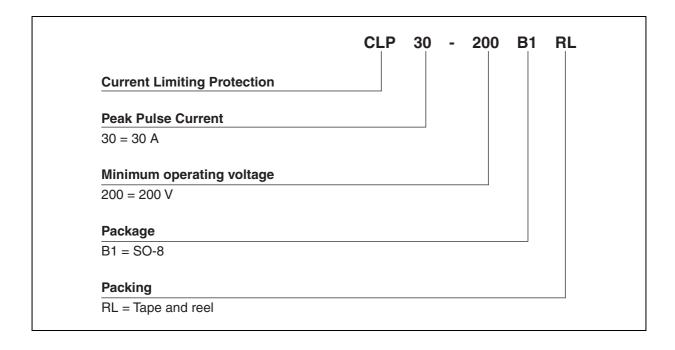
In this case, the positive triggering will be 220 mA min and 320 mA max.

Thanks to the CLP30-200B1 topology, the surge current in the line is reduced after it.

Because the remaining surge energy is low, the power ratings of R<sub>P</sub> the relay contacts and the external voltage reference device may be kept low.

This results in a significant cost reduction for the whole system.

# 3 Ordering information scheme



CLP30-200B1 Package information

# 4 Package information

Table 5. SO-8 dimensions

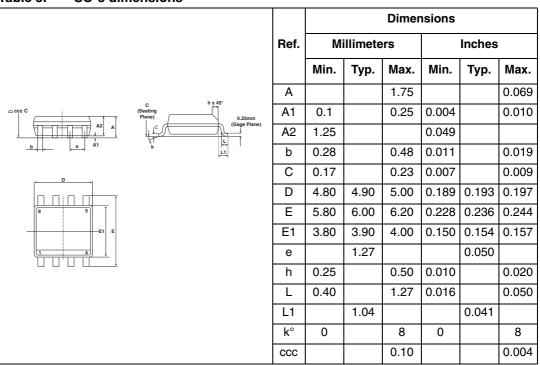
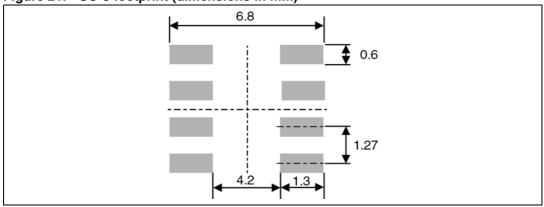


Figure 21. SO-8 footprint (dimensions in mm)



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Ordering information CLP30-200B1

# 5 Ordering information

Part Number	Marking	Package	Weight	Base qty	Delivery mode
CLP30-200B1RL	CLP30	SO-8	0.11 g	2500	Tape and reel

# 6 Revision history

Date	Revision	Description of Changes
28-Aug-2006	1	First issue.

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